

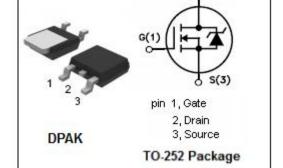
isc N-Channel MOSFET Transistor

IRF630NSTRRPBF

D(2)

DESCRIPTION

- Drain Current –I_D=9.3A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 200V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 0.3 \Omega (Max)$
- · Fast Switching Speed
- · Low Drive Requirement
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

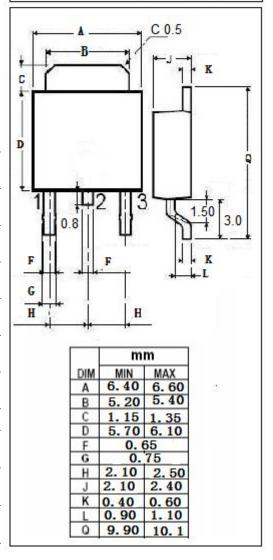
 This device is n-channel, enhancement mode, power MOSFET designed especially for high power, high speed applications, such as switching power supplies, UPS, AC and DC motor controls, relay and solenoid drivers and high energy pulse circuits.



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SYMBOL	PARAMETER VALUE		UNIT				
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	200	V				
V _{GS}	Gate-Source Voltage	±20	V				
I _D	Drain Current-continuous@ TC=25℃	9.3	А				
P _D	Total Dissipation@TC=25°C	82	W				
T _j	Max. Operating Junction Temperature	175	$^{\circ}$				
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$				

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth j-c	Thermal Resistance,Junction to Case	1.83	°C/W
R _{th j-a}	Thermal Resistance,Junction to Ambient	62	°C/W





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• ELECTRICAL CHARACTERISTICS (T_C=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D =0.25mA	200		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	2	4	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D =5.4A		0.3	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} =±20V;V _{DS} =0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =200V; V _{GS} =0		25	uA
V _{SD}	Diode Forward Voltage	I _F = 5.4A; V _{GS} =0		1.3	V

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